

MODULATOR

MPX1300 and MPZ1300 series

Low frequencies to 20 GHz Phase Modulators

The Exail MPX1300 and MPZ1300 series are lithium niobate (LiNbO₃) phase modulators specially designed for operation in the 1310 nm wavelength band. Thanks to their O-Band optimized optical waveguides design and their 1310 nm selected fibers, the MPX1300 and MPZ1300 can be claimed genuine 1310 nm phase modulators.

- The MPZ1300-LN-10 is ideally suited for wide bandwidth operation up to 20 GHz.
- The MPX1300-LN-0.1 has a high impedance input optimized for modulation frequencies up to 300 MHz.



Designed using state-of-the-art and proven lithium niobate technology, MPX1300 and MPZ1300 series phase modulators are easy to operate and to integrate. These modulators come with a comprehensive range of options (DC Coupled, High Electric Power) to offer the highest performance for a wide range of applications from laboratory experiments to demanding industrial systems.

Features

- Low and wide EO bandwidth
- Full O-Band operation
- Low V_{π}
- Low insertion loss

Applications

- Side bands generation
- Laser Combining
- Interferometric sensing
- Frequency shifting / broadening
- Quantum Key Distribution (QKD)
- Pound-Drever-Hall locking (PDH)
- High data rate telecommunications

Options

- DC coupled
- Low residual intensity modulation
- High electrical input power capability
- Optical E and S bands version

Related Equipments

- Matched RF amplifiers
- MX, MXAN, MXER intensity modulators
- Short optical pulse ModBox

MPX1300-LN-0.1 Phase Modulators Highlights

Parameter

Operating wavelength	1270 nm – 1360 nm
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Usable Electro-optical bandwidth	300 MHz
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V_{π} RF @50 kHz	3 V
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Insertion loss	3 dB
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MPZ1300-LN-10 Phase Modulators Highlights

Parameter

Operating wavelength	1270 nm – 1360 nm
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Usable electro-optical bandwidth	20 GHz
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V_{π} RF @50 kHz	4 V
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Insertion loss	3.3 dB
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MPX1300-LN-0.1

Up to 300 MHz Phase Modulator

Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	S_{21}	-	-	150	-	MHz
Usable electro-optical bandwidth	S_{21}	-	-	300	-	MHz
V_{π} RF @50 kHz	$V_{\pi_{RF\ 50\ kHz}}$	-	-	3	3.5	V
RF Input Impedance	Z_{in-RF}	-	-	10 000	-	Ω

Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Waveguide process	-	-	Ti diffusion			
Operating wavelength	λ	-	1270	1310	1360	nm
Insertion loss	IL	Without optical connectors*	-	3	4	dB
Optical return loss	ORL	-	-40	-45	-	dB

All specifications given at 25 °C, 1310 nm, unless differently specified.

(*) Consider an extra-loss up to 0.25 dB for each FC/APC optical connector

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
Modulation voltage range	EV_{in}	-20	+20	V
Optical input power	OP_{in}	-	+20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

MPZ1300-LN-10

Up to 20 GHz Phase Modulator

Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	S_{21}	-	10	12	-	GHz
Usable electro-optical bandwidth	S_{21}	-	-	20	-	GHz
Ripple S_{21}	ΔS_{21}	-	-	0.5	1	dB
Electrical return loss	S_{11}	-	-	-17	-13	dB
		HEP option	-	-14	-10	dB
V π RF @50 kHz	V $\pi_{RF 50 kHz}$	-	-	3.3	4	V
V π RF @10 GHz	V $\pi_{RF 10 GHz}$	-	-	4.5	5.5	V
RF impedance matching	Z $_{in-RF}$	-	-	50	-	Ω
V π DC electrodes	V π_{DC}	DCC option, housing #B	-	3.3	6	V
DC port impedance matching	Z $_{in-DC}$	DCC option, housing #B	1	-	-	M Ω
DC port impedance matching	Z $_{in-DC}$	DCC option only	1	-	-	M Ω

Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate Z-Cut Y-Prop			
Waveguide process	-	-	Ti diffusion			
Operating wavelength	λ	-	1270	1310	1350	nm
Insertion loss	IL	Without optical connectors*	-	2.5	3.5	dB
Optical return loss	ORL	-	-40	-45	-	dB

All specifications given at 25 °C, 1310 nm, unless differently specified.

*⁽¹⁾Consider an extra-loss up to 0.25 dB for each FC/APC optical connector

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Parameter	Symbol	Condition	Min	Typ	Max	Unit
RF input power	EP $_{in}$	-	-	-	+28	dBm
High electrical input power option	HEP $_{in}$	HEP option	-	-	+33	dBm
Optical input power	OP $_{in}$	For optimal performance	-	-	+12	dBm
		Before failure	-	-	+20	dBm
Bias voltage range	V $_{DCC}$	DCC option, housing #B	-15	-	+15	V
Operating temperature	OT	-	0	-	+70	°C
Storage temperature	ST	-	-40	-	+85	°C

